

# **WNSC04650T**

### Silicon Carbide Diode

Rev.01 - 17 March 2020

**Product data sheet** 

### **1. General description**

Silicon Carbide Schottky diode in a DFN 8\*8 plastic package, designed for high frequency switched-mode power supplies.



### 2. Features and benefits

- Highly stable switching performance
- High forward surge capability IFSM
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

### 3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

# 4. Quick reference data

Table 1. Q	uick reference data					
Symbol	Parameter	Conditions	Values			Unit
Absolute	maximum rating					
$V_{\text{RRM}}$	repetitive peak reverse voltage		6	50		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T <sub>c</sub> ≤ 150 °C; Fig. 1; Fig. 2; Fig. 3	4		A	
Tj	junction temperature		175		°C	
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>	-	1.5	1.7	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>	-	1.8	2.1	V
Dynamic	characteristics					
Q <sub>r</sub>	recovered charge	$I_F = 4 \text{ A}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s}; V_R = 400 \text{ V};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-	7	-	nC

# 5. Pinning information

Table 2.	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected	[]	к-Ң-А
2	n.c.	not connected	5	001aaa020
3	А	anode		
4	A	anode	8 a a a	
5	К	mounting base; connected to cathode	$\begin{bmatrix} Q_1 & \hline & & & \hline & & & \hline & & & & \hline & & & & \hline & & & & & & \hline & & & & & & \hline & & & & & \hline & & & & & \hline & & & & & & \hline & & & \hline & & & \hline & & & \hline & & & & \hline & & & \hline & & & \hline & & & & \hline & & & & \hline & & \hline & & \hline & & & \hline & & & \hline & \hline & \hline & & \hline & \hline & \hline & \hline & \hline \\ \hline & & \hline & \hline$	

# 6. Ordering information

Table 3. Ordering information								
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
WNSC04650T	DFN8*8	WNSC04650T6J	Таре	3000	DFN8X8N	25-Dec-2019		

# 7. Marking

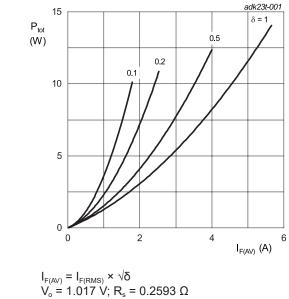
Table 4. Marking codes					
Type number	Marking codes				
WNSC04650T	WNSC				
	04650T				

# 8. Limiting values

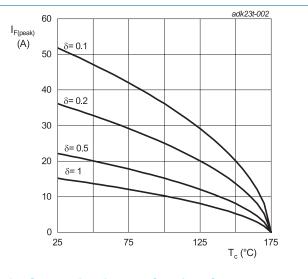
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{\text{RRM}}$	repetitive peak reverse voltage		650	V
V <sub>RWM</sub>	crest working reverse voltage		650	V
V <sub>R</sub>	reverse voltage	DC	650	V
$\mathbf{I}_{F(AV)}$	average forward current	δ = 0.5; square-wave pulse; T <sub>c</sub> ≤ 150 °C; Fig. 1; Fig. 2; Fig. 3	4	A
I <sub>FRM</sub>	repetitive peak forward current	δ = 0.5; t <sub>p</sub> = 25 μs; T <sub>c</sub> ≤ 150 °C; square-wave pulse	8	A
I <sub>FSM</sub>	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	24	А
	forward current	$t_p$ = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse	235	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	sine-wave pulse; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms	3	A <sup>2</sup> s
T <sub>stg</sub>	storage temperature		-55 to 175	°C
T <sub>j</sub>	junction temperature		175	°C

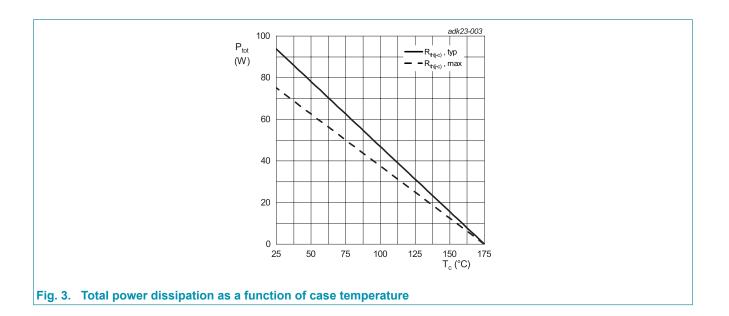


 $V_o = 1.017$  V;  $R_s = 0.2593$  Ω Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



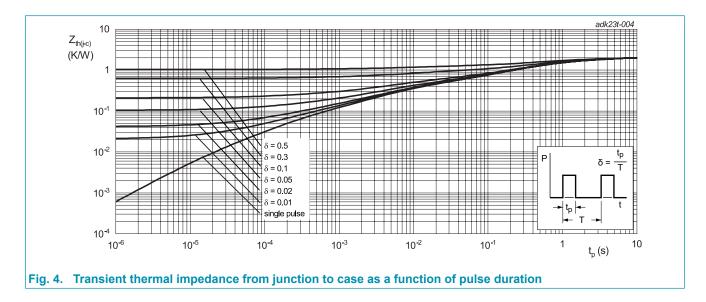


### WNSC04650T Silicon Carbide Diode



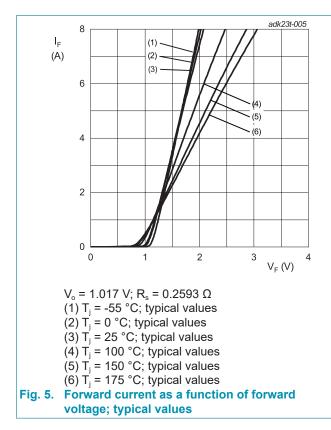
# 9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	Fig. 4	-	1.6	2	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W



### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V <sub>F</sub>	forward current	I <sub>F</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>	-	1.5	1.7	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>	-	1.8	2.1	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 175 °C; <u>Fig. 5</u>		2	2.25	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 650 V; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-		25	μA
		V <sub>R</sub> = 650 V; T <sub>j</sub> = 175 °C; <u>Fig. 6</u>	-		100	μA
Dynamic	characteristics	· · ·	I			
Q <sub>r</sub>	recovered charge	$I_F = 4 \text{ A}; V_R = 400 \text{ V}; \text{ d}_F/\text{d}t = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-	7	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C	-	141	-	pF
		f = 1 MHz; V <sub>R</sub> = 300 V; T <sub>j</sub> = 25 °C	-	23	-	pF
		f = 1 MHz; V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	22	-	pF
E <sub>as</sub>	non-repetitive avalanche energy	I <sub>R</sub> = 3.5 A; L = 5 mH; T <sub>j(init)</sub> = 25 °C	30	-	-	mJ



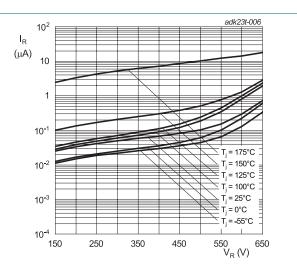
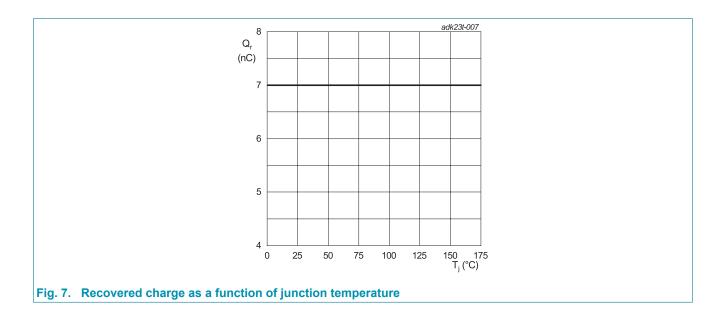
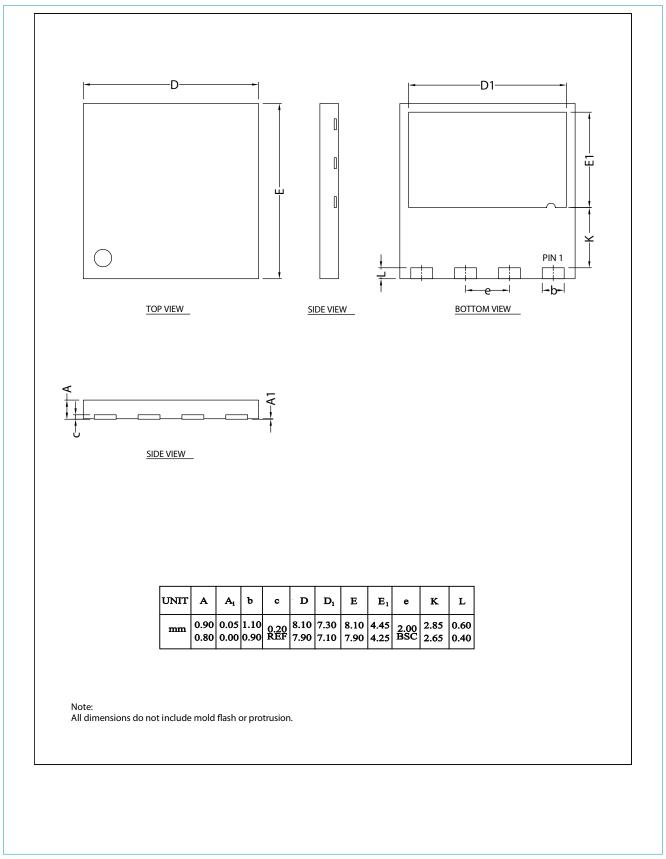


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value



# 11. Package outline



# 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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